



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SA2210 — PNP Epitaxial Planar Silicon Transistor — High-Current Switching Applications

Applications

- Relay drivers, lamp drivers, motor drivers.

Features

- Adoption of MBIT processes
- Low collector-to-emitter saturation voltage
- Large current capacitance
- High-speed switching

Specifications

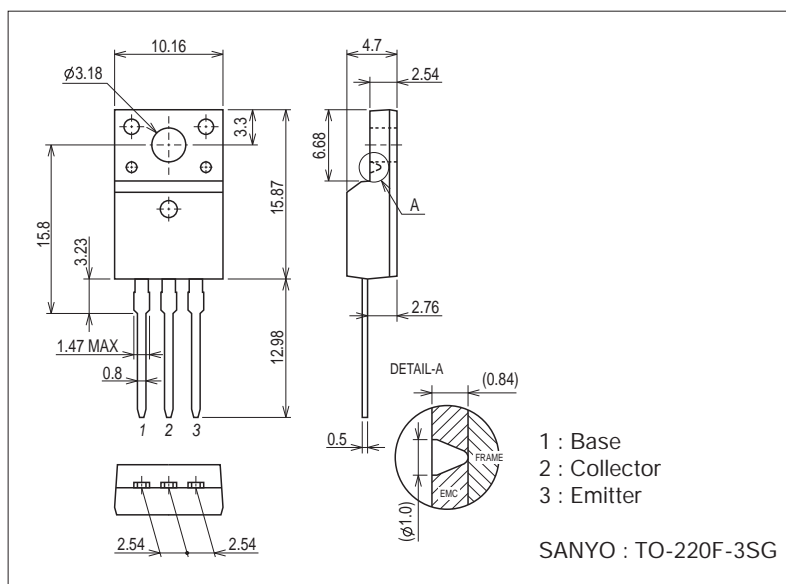
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-50	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	VEBO		-6	V
Collector Current	IC		-20	A
Collector Current (Pulse)	ICP		-25	A
Base Current	IB		-3	A
Collector Dissipation	PC		2	W
		Tc=25°C	30	W
Junction Temperature	TJ		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ)

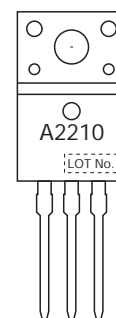
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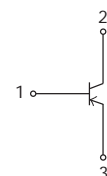
Product & Package Information

- Package : TO-220F-3SG
- JEITA, JEDEC : SC-67
- Minimum Packing Quantity : 50 pcs./magazine

Marking



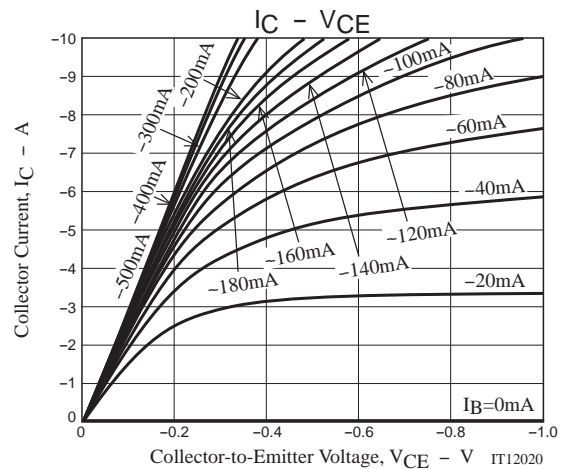
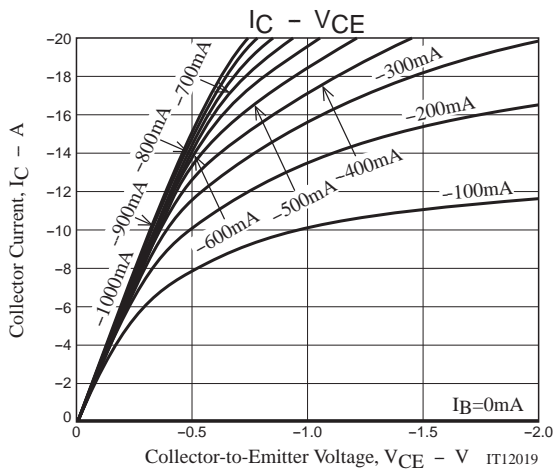
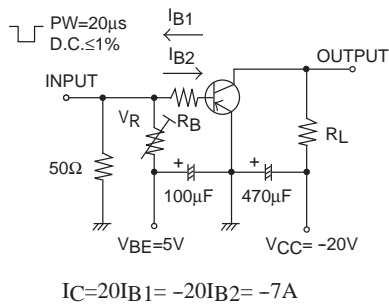
Electrical Connection

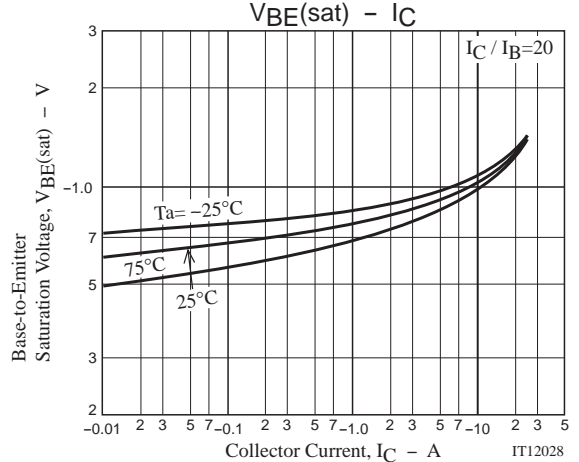
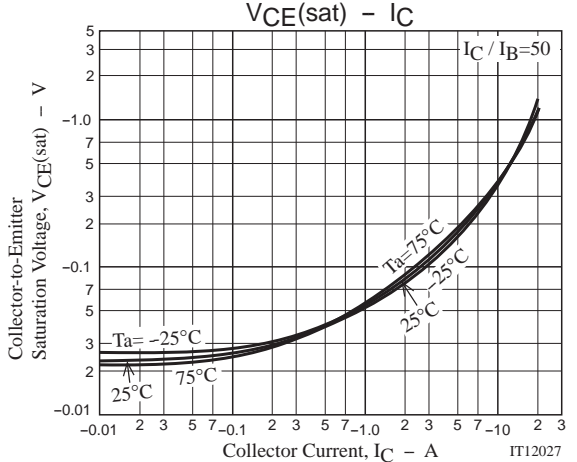
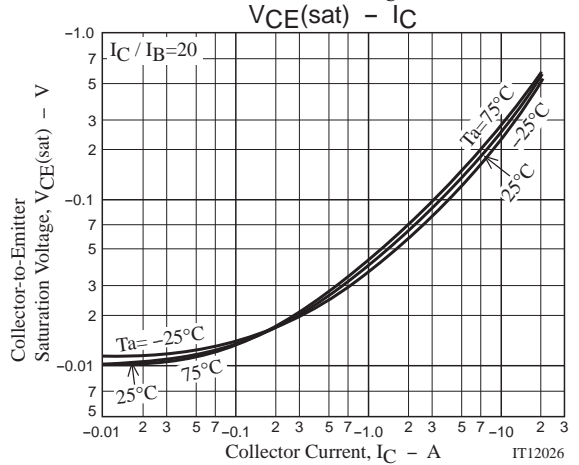
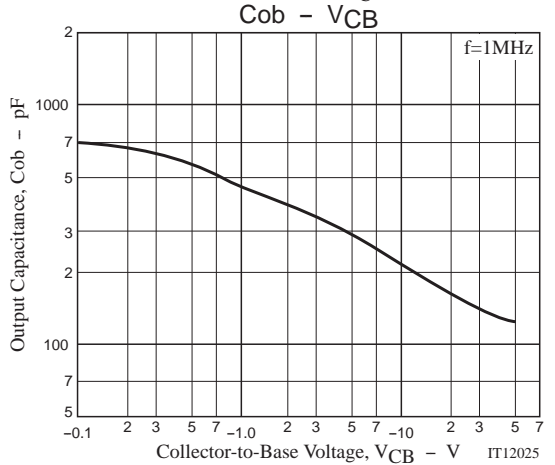
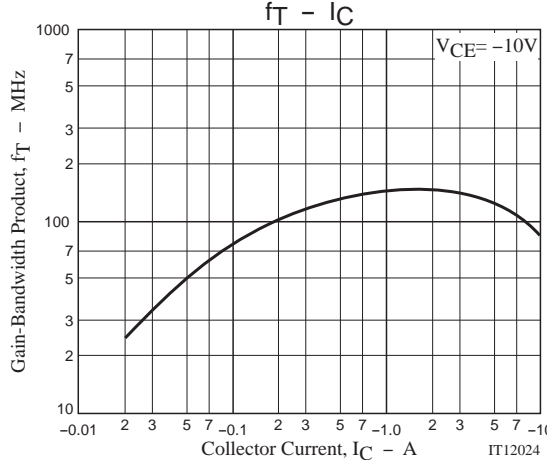
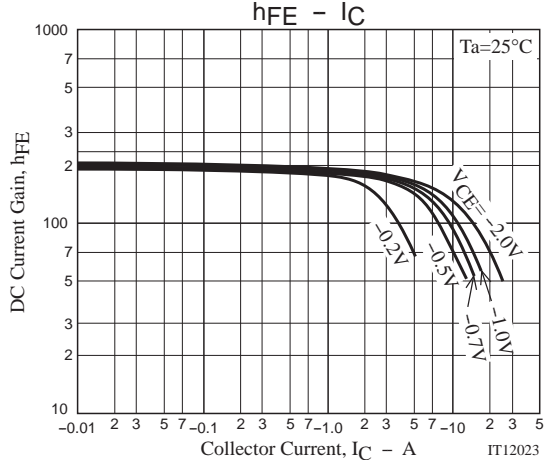
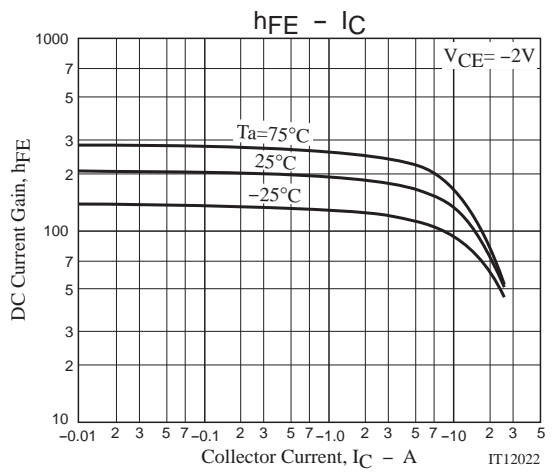
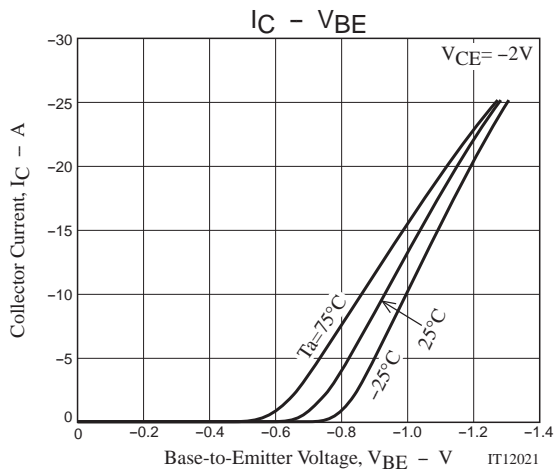


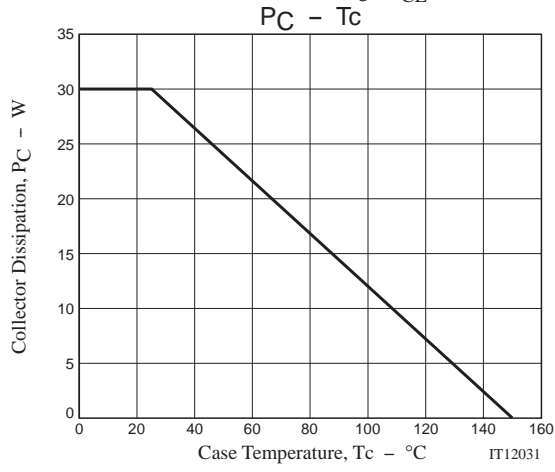
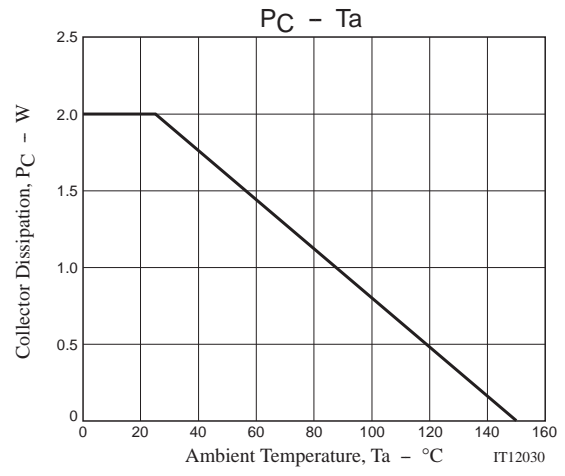
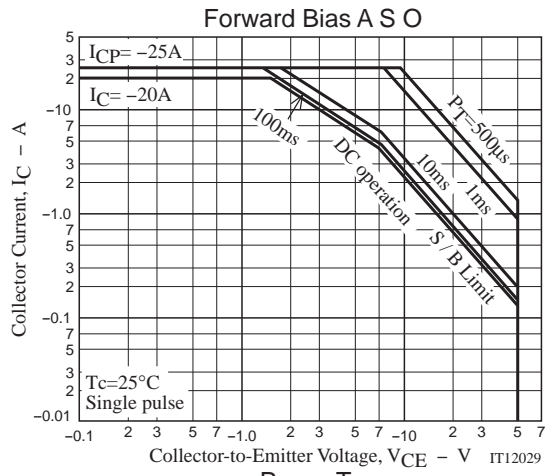
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = -40V, I_E = 0A$			-10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -4V, I_C = 0A$			-10	μA
DC Current Gain	h_{FE}	$V_{CE} = -2V, I_C = -1A$	150		450	
Gain-Bandwidth Product	f_T	$V_{CE} = -10V, I_C = -1A$		140		MHz
Output Capacitance	C_{ob}	$V_{CB} = -10V, f = 1MHz$		215		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -7A, I_B = -350mA$		-200	-500	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -7A, I_B = -350mA$			-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0A$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0A$	-6			V
Turn-On Time	t_{on}	See specified Test Circuit		60		ns
Storage Time	t_{stg}	See specified Test Circuit		270		ns
Fall Time	t_f	See specified Test Circuit		20		ns

Switching Time Test Circuit







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